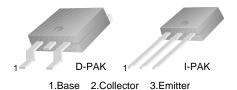


November 2010

MJD31/31C NPN Epitaxial Silicon Transistor

Features

- General Purpose Amplifier
- Low Speed Switching Applications
- Load Formed for Surface Mount Application (No Suffix)
- Straight Lead (I-PAK, "- I" Suffix)
- Electrically Similar to Popular TIP31 and TIP31C



Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter		Value	Units	
V _{CBO}	Collector-Base Voltage	: MJD31	40	V	
		: MJD31C	100	V	
V _{CEO}	Collector-Emitter Voltage	: MJD31	40	V	
		: MJD31C	100	V	
V_{EBO}	Emitter-Base Voltage		5	V	
I _C	Collector Current (DC)	3	Α		
I _{CP}	Collector Current (Pulse)	5	А		
Ι _Β	Base Current	1	А		
P _C	Collector Dissipation (T _C =25°C)		15	W	
	Collector Dissipation (T _a =25°C)		1.56	W	
T _J	Junction Temperature		150	°C	
T _{STG}	Storage Temperature		- 65 to 150	°C	

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
V _{CEO} (sus)	* Collector-Emitter Sustaining Voltage				
	: MJD31	$I_C = 30 \text{mA}, I_B = 0$	40		V
	: MJD31C	$I_C = 30 \text{mA}, I_B = 0$	100		V
I _{CEO}	Collector Cut-off Current				
	: MJD31	$V_{CE} = 40V, I_{B} = 0$		50	μΑ
	: MJD31C	$V_{CE} = 60V, I_{B} = 0$		50	μΑ
I _{CES}	Collector Cut-off Current				
	: MJD31	$V_{CE} = 40V, V_{BE} = 0$		20	μΑ
	: MJD31C	$V_{CE} = 100V, V_{BE} = 0$		20	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{BE} = 5V, I_{C} = 0$		1	mA
h _{FE}	* DC Current Gain	$V_{CE} = 4V$, $I_{C} = 1A$	25		
		$V_{CE} = 4V, I_{C} = 3A$	10	50	
V _{CE} (sat)	* Collector-Emitter Saturation Voltage	I _C = 3A, I _B = 375mA		1.2	V
V _{BE} (on)	* Base-Emitter On Voltage	$V_{CE} = 4A, I_{C} = 3A$		1.8	V
f _T	Current Gain Bandwidth Product	$V_{CE} = 10V, I_{C} = 500mA$	3		MHz

^{*} Pulse Test: PW≤300μs, Duty Cycle≤2%

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MJD31/31C Rev. A3

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Typical Performance Characteristics

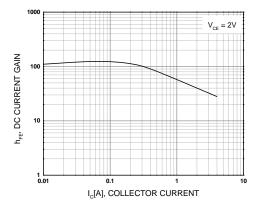


Figure 1. DC current Gain

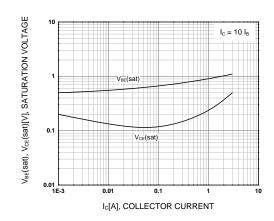


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

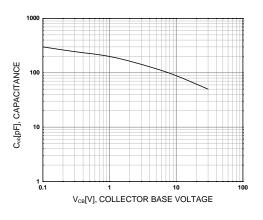
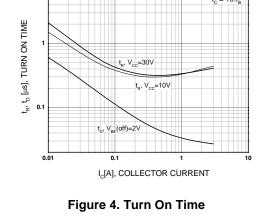


Figure 3. Collector Capacitance



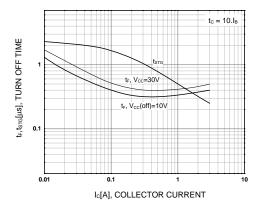


Figure 5. Turn Off Time

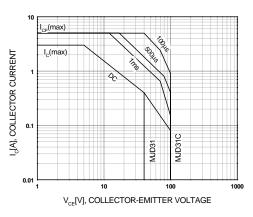


Figure 6. Safe Operating

Typical Performance Characteristics (Continued)

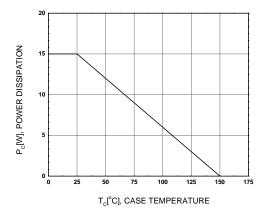
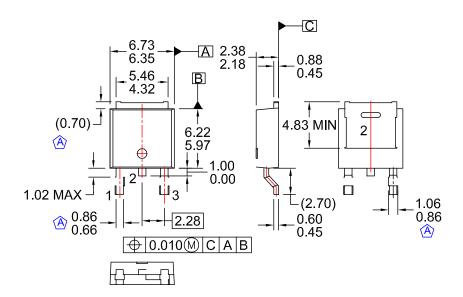


Figure 7. Power Derating

Physical Dimensions

D-PAK



NOTES: UNLESS OTHERWISE SPECIFIED

(A) CONFORMS TO JEDEC TO-252 VARIATION AB EXCEPT WHERE NOTED

- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DRAWING CONFORMS TO ASME Y14.5M-1994
- D) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- E) FORMERLY NAMED BD1733
- F) DRAWING FILE NAME: MKT-TO252D03REV1

Dimensions in Millimeters





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Definition of Terms					
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